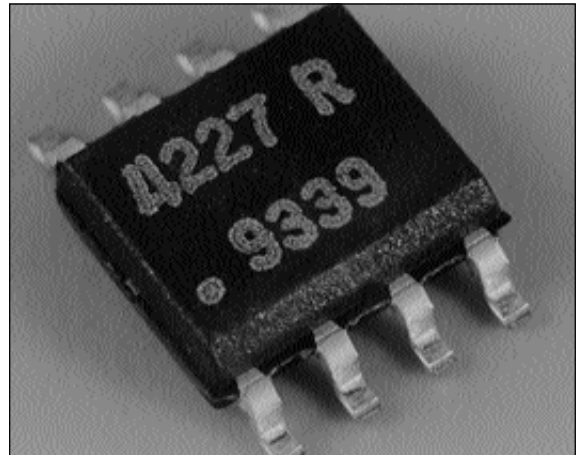


# GaAs MMIC SPDT Reflective Switch, DC - 3GHz



## Features

- Broadband performance
- High Isolation; 40dB typ at 1GHz
- Ultra low DC power consumption
- Fast switching speed; 3ns typical
- SO8 surface mount plastic package

## Description

The P35-4227-3R is a high performance Gallium Arsenide single pole double throw broadband RF switch. It is suitable for use in broadband communications and instrumentation applications. A short circuit reflective termination is presented at the isolated output of the switch. The switch is controlled by the application of complimentary 0V/-5V or 0/-8V signals to the control lines in accordance with the truth table below.

This die is fabricated using MOC's 0.5 $\mu$ m gate length MESFET process (S20) and is fully protected using Silicon Nitride passivation for excellent performance and reliability. This device is packaged in a low-cost SO8 surface mount plastic package.

## Electrical Performance

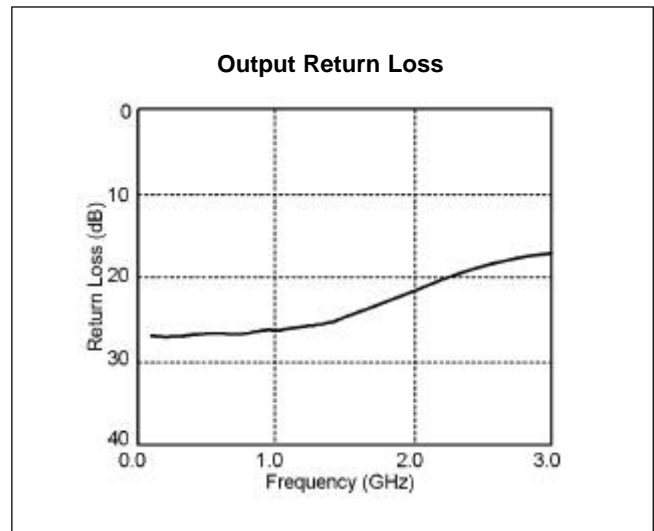
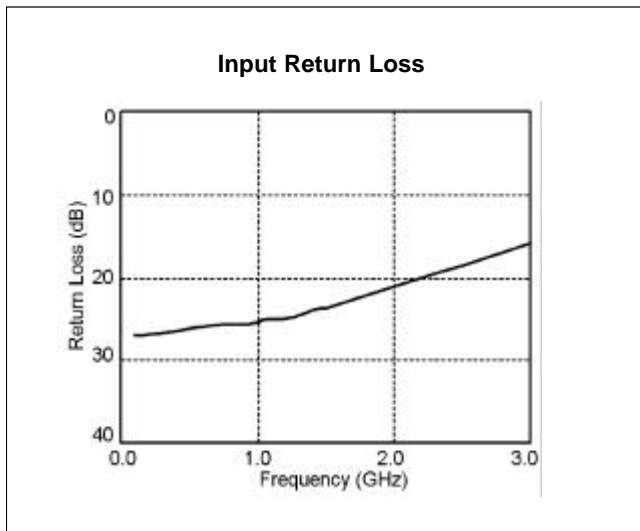
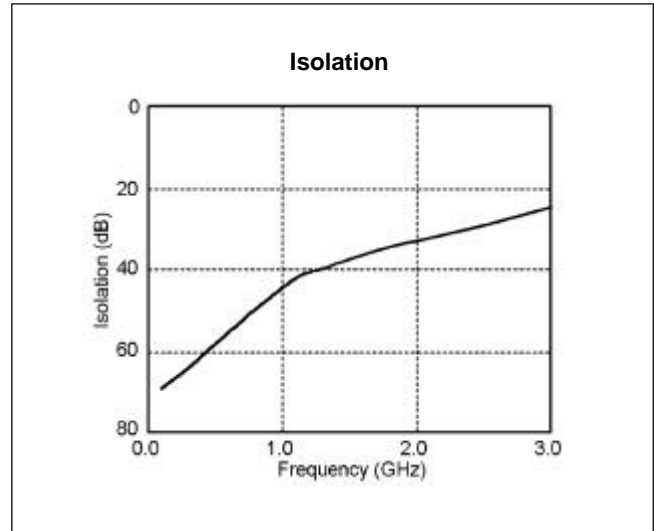
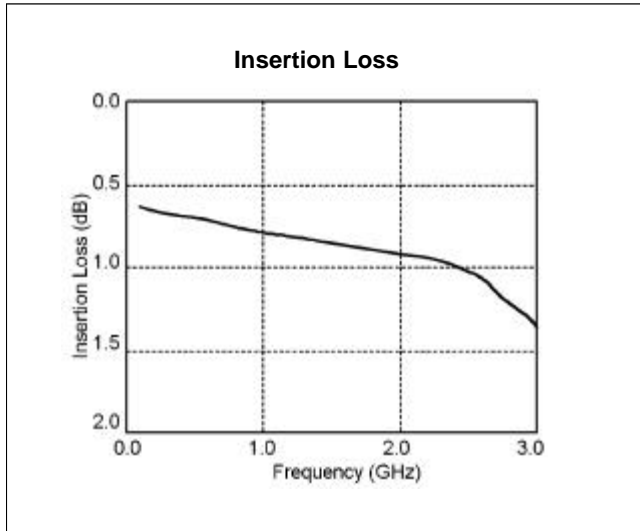
Ambient temperature = 22 $\pm$ 3 $^{\circ}$ C ,  $Z_O$  = 50 $\Omega$ , Control voltages = 0V/-5V unless otherwise stated

Parameter	Conditions	Min	Typ	Max	Units
Insertion Loss	DC - 1GHz	-	1.0	1.2	dB
	1 - 3GHz	-	1.4	1.5	dB
Isolation	DC - 1GHz	38	40	-	dB
	1 - 3GHz	22	23	-	dB
Input Return Loss <sup>1</sup>	DC - 1GHz	20	25	-	dB
	1 - 3GHz	12	16	-	dB
Output Return Loss <sup>1</sup>	DC - 1GHz	20	26	-	dB
	1 - 3GHz	12	17	-	dB
1dB power compression point <sup>2</sup>	0/-5V Control; 50MHz	-	20	-	dBm
	0/-5V Control; 2GHz	-	27	-	dBm
	0/-8V Control; 50MHz	-	22	-	dBm
	0/-8V Control; 2GHz	-	30	-	dBm
Switching Speed	50% Control to 10%90%RF	-	3	8	ns

## Notes

1. Return Loss measured in low loss switch state.
2. Input power at which insertion loss compresses by 1dB.

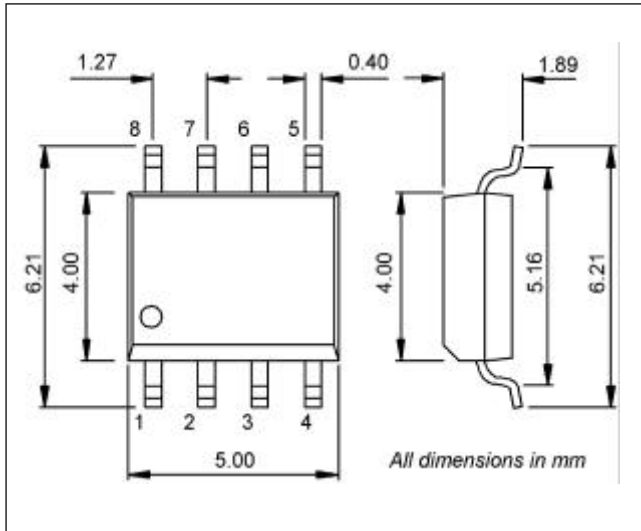
## Typical Performance at 22°C



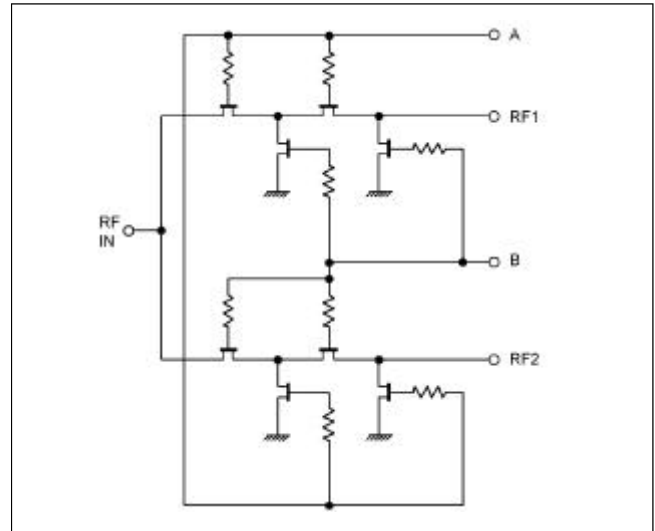
## Absolute Maximum Ratings

Max control voltage	-8V
Max I/P power	+30 dBm
Operating temperature	-40°C to +85°C
Storage temperature	-65°C to +150°C

**Package Outline**



**Electrical Schematic**



**Pin Details**

Pin	Function
1	RF IN
2	Ground
3	RF2
4	Control B
5	Control A
6	RF1
7	Ground
8	Ground

**Switching Truth Table**

A	B	RF IN-RF1	RF IN-RF 2
0V	-5V	Low Loss	Isolated
-5V	0V	Isolated	Low Loss

**Ordering Information: P35-4227-3R**

The data and product specifications are subject to change without notice. These devices should not be used for device qualification and production without prior notice.

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The Marconi logo features the word "Marconi" in a stylized, cursive script font. The letter "M" is particularly large and ornate, with a long horizontal stroke that extends to the right and underlines the rest of the word. The letters "a", "r", "c", "o", "n", and "i" are written in a more traditional, slightly rounded script.

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